# MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

BAS70/-04/-05/-06

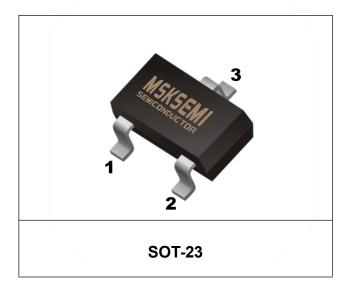
**Product specification** 



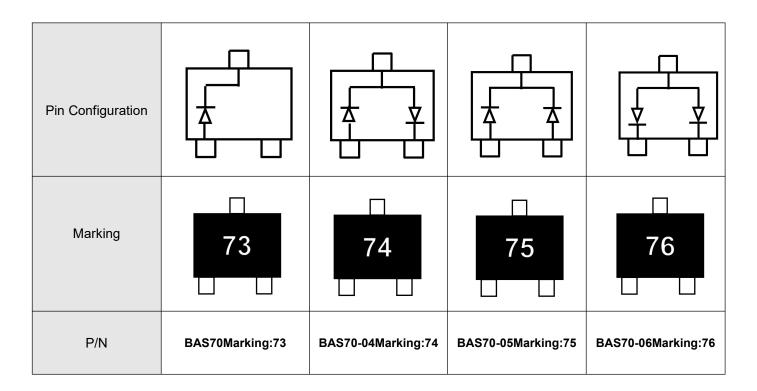


## **Features**

- Low turn-on voltage
- Fast switching
- Also available in lead free version



#### **Reference News**





## MAXIMUM RATINGS@Ta=25℃

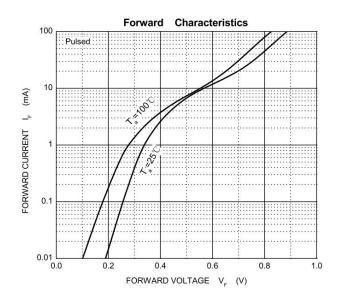
Symbol	Parameter	Value	Unit
VR	DCVoltage	70	V
lF	ForwardContinuousCurrent	70	mA
IFSM	Non-RepetitivePeakForwardSurgeCurrent@ t=8.3ms	100	mA
Po	PowerDissipation	200	mW
R <sub>9JA</sub>	ThermalResistanceJunctiontoAmbient	500	°C/W
TJ	OperatingJunctionTemperatureRange	-40~+125	$^{\circ}$
Tstg	StorageTemperatureRange	-55~+150	$^{\circ}$

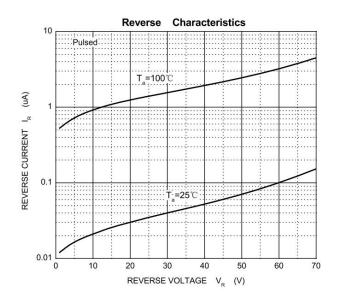
## **ELECTRICALCHARACTERISTICS**(Ta=25 °C unless otherwise specified)

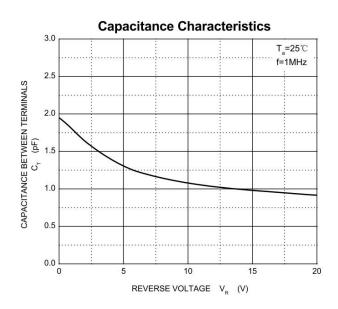
Parameter	Symbol	Testconditions	Min	Max	Unit
Reverse breakdown voltage	V <sub>(BR)</sub>	I <sub>R</sub> = 10 u A	70		V
Reverse voltage leakage current	l <sub>R</sub>	V <sub>R</sub> =50V		100	nA
Forward voltage	VF	I <sub>F</sub> =1mA I <sub>F</sub> =15mA		410 1000	mV
Diode cap acitance	C <sub>D</sub>	$V_R = 0Vf = 1MHz$		2	pF
Reveres recovery time	trr	I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>rr</sub> = 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100 Ω		5	ns

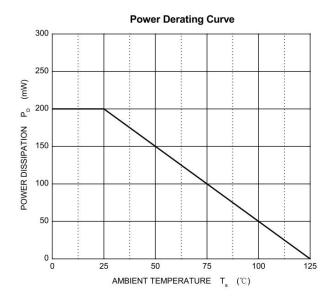


#### **ELECTRICAL CHARACTERISTICS CURVE**



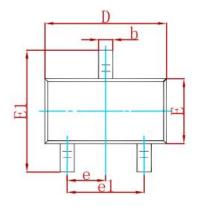


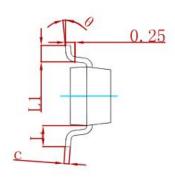


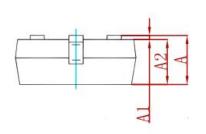




#### PACKAGE MECHANICAL DATA

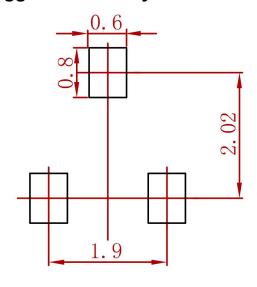






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# **Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
BAS70/-04/-05/-06	SOT-23	3000



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